

L Number	Hits	Search Text	DB	Time stamp
1	20010	semiconductor and (tft or (thin adj film adj transistor))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/09/06 13:23
2	3013	(semiconductor and (tft or (thin adj film adj transistor))) and (cmos or complementary)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/09/06 13:23
3	877	((semiconductor and (tft or (thin adj film adj transistor))) and (cmos or complementary)) and (ldd or (lightly adj doped adj drain))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/09/06 13:28
4	869	((semiconductor and (tft or (thin adj film adj transistor))) and (cmos or complementary)) and (ldd or (lightly adj doped adj drain)) ) and gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/09/06 13:29
5	858	((((semiconductor and (tft or (thin adj film adj transistor))) and (cmos or complementary)) and (ldd or (lightly adj doped adj drain)) ) and gate) and (electrode or wir\$3 or conduct\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/09/06 13:30
6	589	((((semiconductor and (tft or (thin adj film adj transistor))) and (cmos or complementary)) and (ldd or (lightly adj doped adj drain)) ) and gate) and (electrode or wir\$3 or conduct\$3)) and (lcd or (liquid adj crystal adj display))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/09/06 13:32